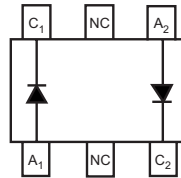
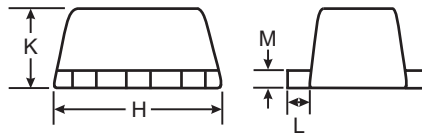
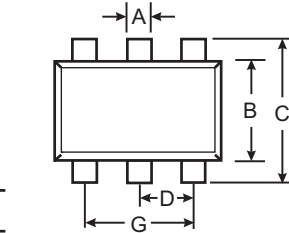


Features

- Low Forward Voltage Drop
- Fast Switching
- PN Junction Guard Ring for Transient and ESD Protection
- **Lead Free By Design/RoHS Compliant (Note 1)**
- **"Green" Device (Note 4)**

Mechanical Data

- Case: SOT-563
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture sensitivity: Level 1 per J-STD-020C
- Terminal Connections: See Diagram
- Terminals: Finish — Matte Tin annealed over Alloy 42 leadframe. Solderable per MIL-STD-202, Method 208
- Marking & Type Code Information: See Last Page
- Ordering Information: See Last Page
- Weight: 0.003 grams (approx.)



SOT-563			
Dim	Min	Max	Typ
A	0.15	0.30	0.25
B	1.10	1.25	1.20
C	1.55	1.70	1.60
D	0.50		
G	0.90	1.10	1.00
H	1.50	1.70	1.60
K	0.56	0.60	0.60
L	0.10	0.30	0.20
M	0.10	0.18	0.11
All Dimensions in mm			

Maximum Ratings @ $T_A = 25^\circ\text{C}$ unless otherwise specified

Characteristic	Symbol	Value	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V_{RRM} V_{RWM} V_R	40	V
Forward Continuous Current (Note 2)	I_{FM}	200	mA
Forward Surge Current (Note 2) @ $t < 1.0\text{s}$	I_{FSM}	600	mA
Operating Temperature Range	T_j	-55 to +125	$^\circ\text{C}$
Storage Temperature Range	T_{STG}	-65 to +150	$^\circ\text{C}$

Thermal Characteristics @ $T_A = 25^\circ\text{C}$ unless otherwise specified

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 2)	P_d	150	mW
Thermal Resistance, Junction to Ambient Air (Note 2)	$R_{\theta JA}$	833	$^\circ\text{C}/\text{W}$

Electrical Characteristics @ $T_A = 25^\circ\text{C}$ unless otherwise specified

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
Reverse Breakdown Voltage (Note 3)	$V_{(BR)R}$	40	—	—	V	$I_R = 10\mu\text{A}$
Forward Voltage	V_F	—	—	380 1000	mV	$t_p < 300\mu\text{s}$, $I_F = 1.0\text{mA}$ $t_p < 300\mu\text{s}$, $I_F = 40\text{mA}$
Reverse Leakage Current (Note 3)	I_R	—	20	200	nA	$t_p < 300\mu\text{s}$, $V_R = 30\text{V}$
Total Capacitance	C_T	—	4.0	5.0	pF	$V_R = 0\text{V}$, $f = 1.0\text{MHz}$
Reverse Recovery Time	t_{rr}	—	—	5.0	ns	$I_F = I_R = 10\text{mA}$ to $I_R = 1.0\text{mA}$, $R_L = 100\Omega$

- Note:
1. No purposefully added lead.
 2. Part mounted on FR-4 board with recommended pad layout, which can be found on our website at <http://www.diodes.com/datasheets/ap02001.pdf>.
 3. Short duration test pulse used to minimize self-heating effect.
 4. Diodes Inc.'s "Green" policy can be found on our website at http://www.diodes.com/products/lead_free/index.php.

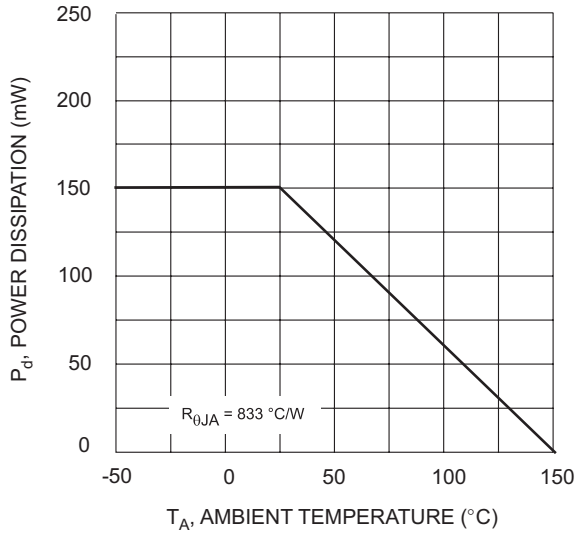


Fig. 1, Derating Curve - Total

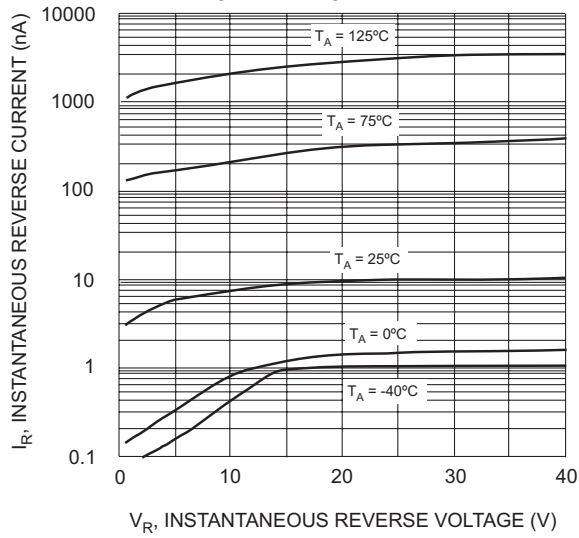


Fig. 3 Typical Reverse Characteristics

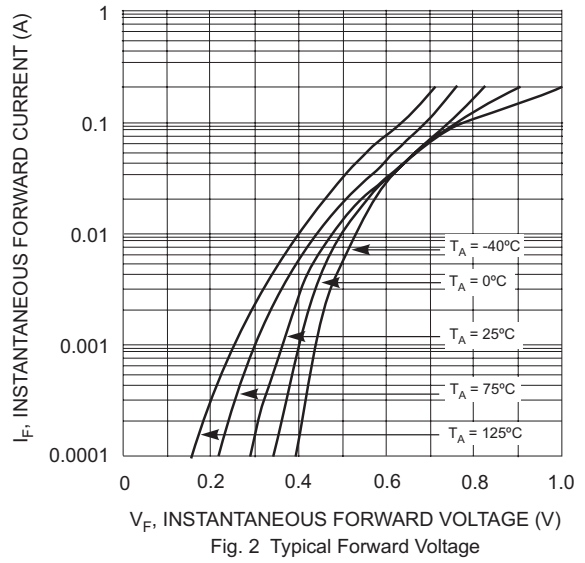


Fig. 2 Typical Forward Voltage

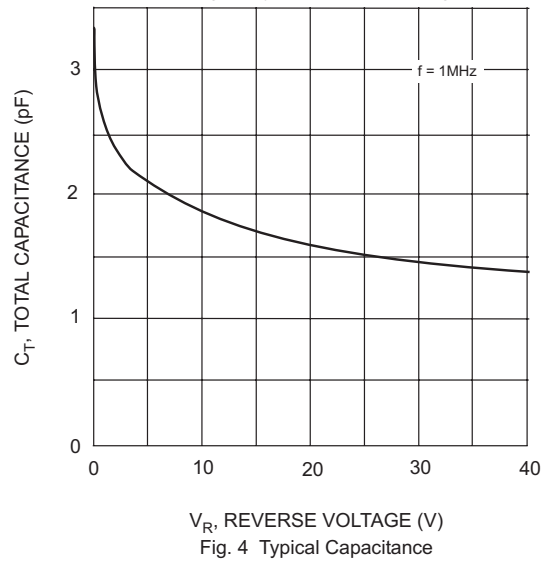


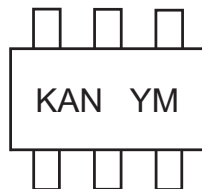
Fig. 4 Typical Capacitance

Ordering Information (Note 4)

Device	Packaging	Shipping
BAS40V-7	SOT-563	3000/Tape & Reel

Notes: 4. For Packaging Details, go to our website at <http://www.diodes.com/datasheets/ap02007.pdf>.

Marking Information



KAN = Product Type Marking Code
 YM = Date Code Marking
 Y = Year (ex: R = 2004)
 M = Month ex: 9 = September

Date Code Key

Year	2004	2005	2006	2007	2008	2009	2010	2011	2012
Code	R	S	T	U	V	W	X	Y	Z

Month	Jan	Feb	March	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	O	N	D

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